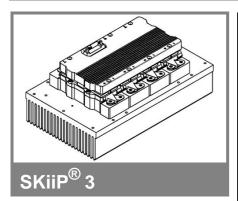
SKiiP 2013GB122-4DL



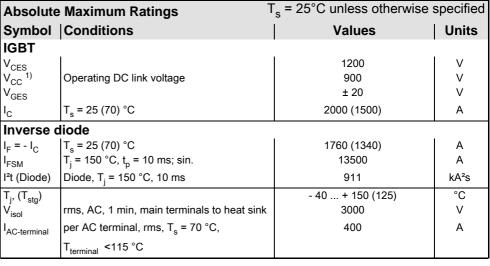
2-pack-integrated intelligent Power System

Power section SKiiP 2013GB122-4DL

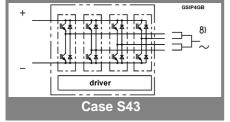
Data

Power section features

- SKiiP technology inside
- SPT (Soft Punch Trough) IGBTs
- CAL diode technology
- Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- IEC 60721-3-3 (humidity) class 3K3/IE32 (SKiiP[®] 3 System)
- IEC 60068-1 (climate) 40/125/56
- UL recognized File no. E63532
- with assembly of suitable MKP capacitor per terminal
- 8) AC connection busbars must be connected by the user; copper busbars available on request

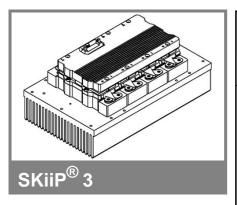


Characte	Characteristics				$T_s = 25$ °C unless otherwise specified			
Symbol	Condition	ons			min.	typ.	max.	Units
IGBT								
V _{CEsat}	I _C = 1200 a measured at t	A, T _j = 25 (erminal	(125) °C;			2,3 (2,5)	2,6	V
V_{CEO}	$T_i = 25 (12)$	25) °C; at to	erminal			1,1 (1)	1,3 (1,2)	V
r_{CE}	$T_j = 25 (12)$					1 (1,2)	1,1 (1,4)	mΩ
I _{CES}	$V_{GE} = 0 V_1$ $T_1 = 25 (12)$, V _{CE} = V _{CI} 25) °C	ES,			4,8 (144)		mA
E _{on} + E _{off}	$I_{\rm C}^{\rm J} = 1200$		00 V			360		mJ
	T _j = 125 °C	C, V _{CC} = 90	00 V			635		mJ
R _{CC+EE}	terminal cl	nip, T _j = 25	S°C			0,13		mΩ
L _{CE}	top, bottor	n				3		nH
C _{CHC}	per phase	, AC-side				6,8		nF
Inverse o								
$V_F = V_{EC}$	I _F = 1200 in measured at t		(125) °C			1,95 (1,7)	2,1	V
V_{TO}	T _i = 25 (12	25) °C				1,1 (0,8)	1,2 (0,9)	V
r _T	$T_i^J = 25 (12)$					0,7 (0,8)	0,8 (0,9)	mΩ
E _{rr}	$I_{\rm C} = 1200$	$A, V_{CC} = 6$	00 V			96		mJ
	T _j = 125 °C	$C, V_{CC} = 90$	00 V			122		mJ
Mechani								
M_{dc}	DC termin				6		8	Nm
M _{ac}	AC termin	-			13	0.4	15	Nm
W	SKiiP® 3 S	system w/o	heat sink			3,1		kg
W	heat sink					9,7		kg
						SKF 16B- nperature		s"
	per IGBT	SIIIK, I	reiere	iice to bi	ייינים נפו 	iiperature	0,015	K/W
$R_{th(j-s)l}$ $R_{th(j-s)D}$	per diode						0,029	K/W
Z _{th}	R _i (mK/W) (max. values)			l				
41	1 '` '	2	[′] 3	4	1	tau 2	3	4
$Z_{\text{th(j-r)I}}$	5,6	6	6,4	0	363	0,18	0,04	1
$Z_{\text{th(j-r)D}}$	10	8,4	14,8	14,8	50	5	0,25	0,04
Z _{th(r-a)}	3,1	17,3	3,7	0,9	230	78	13	0,4



^{*} The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.

SKiiP 2013GB122-4DL



2-pack-integrated intelligent Power System

2-pack integrated gate driver SKiiP 2013GB122-4DL

Data

Gate driver features

- CMOS compatible inputs
- Wide range power supply
- Integrated circuitry to sense phase current, heat sink temperature and

DC-bus voltage (option)

- Short circuit protection
- Over current protection
- Over voltage protection (option)
- Power supply protected against under voltage
- · Interlock of top/bottom switch
- Isolation by transformers
- Fibre optic interface (option for GB-types only)
- IEC 60068-1 (climate) 40/85/56
- UL recognized file no. 242581

Absolute	Maximum Ratings	T _a = 25°C unless otherwise specified		
Symbol	Conditions	Values	Units	
V_{S2}	unstabilized 24 V power supply	30	V	
V_{i}	input signal voltage (high)	15 + 0,3	V	
dv/dt	secondary to primary side	75	kV/μs	
V_{isollO}	input / output (AC, rms, 2s)	3000	V	
V _{isoIPD}	partial discharge extinction voltage, rms, Q _{PD} ≤10 pC;	1170	V	
V _{isol12}	output 1 / output 2 (AC, rms, 2s)	1500	V	
f _{sw}	switching frequency	8	kHz	
f _{out}	output frequency for I _{peak(1)} =I _C	8	kHz	
$T_{op} (T_{stg})$	operating / storage temperature	- 40 + 85	°C	

Characte	eristics	(T _a = 25°C)			
Symbol	Conditions	min.	typ.	max.	Units
V_{S2}	supply voltage non stabilized	13	24	30	V
I _{S2}	V _{S2} = 24 V	324+39*f/kHz+0,00011*(I _{AC} /A) ²			mA
V _{iT+}	input threshold voltage (High)			12,3	V
V_{iT-}	input threshold voltage (Low)	4,6			V
R _{IN}	input resistance		10		kΩ
C_{IN}	input capacitance		1		nF
t _{d(on)IO}	input-output turn-on propagation time		1,3		μs
t _{d(off)IO}	input-output turn-off propagation time		1,3		μs
tpERRRESET	error memory reset time		9		μs
t_{TD}	top / bottom switch interlock time		3,3		μs
I _{analogOUT}	max. 5mA; 8 V corresponds to 15 V supply voltage for external components		2000		Α
I _{s1out}	max. load current			50	mA
I _{TRIPSC}	over current trip level (I _{analog} OUT = 10 V)		2500		А
T_tp	over temperature protection	110		120	°C
UDCTRIP	U_{DC} -protection ($U_{analog OUT} = 9 V$);	i	not mplemented	d	V
	(option for GB types)				

For electrical and thermal design support please use SEMISEL. Access to SEMISEL is via SEMIKRON website http://www.semikron.com.

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